Claims

- 1. A high voltage pulse generating circuit comprising:
- a DC voltage source having first and second output terminals;
- a first switch having one end connected to said first output terminal of said DC voltage source;
- a branch circuit including a free-wheel diode connected across the other end of said first switch and said second output terminal of the DC voltage source; and
- a series circuit including an inductance and a second switch and being connected in parallel with said branch circuit;

wherein after making said first and second switches on to store inductive energy in said inductance, the energy stored in the inductance is commutated to a load connected across said second switch by turning-off said first and second switches

- The high voltage pulse generating circuit according to claim 1, wherein said first and second switches are formed by first and second semiconductor switches, respectively.
- The high voltage pulse generating circuit according to claim 2, wherein suid first and second switches are formed by first and second semiconductor switches having turn-on and -off faculty.
- 4. The high voltage pulse generating circuit according to claim 3, wherein said first semiconductor switch is constituted by a semiconductor switching element having a low withstand voltage, said second semiconductor switch is constructed by a series circuit of a plurality of semiconductor switching elements having a high withstand voltage, the number of which is determined in accordance with an amplitude of an output voltage pulse to be generated, said circuit further comprises a plurality of iron cores, the number of which is equal to that of said plurality of semiconductor switching elements, a primary winding passing through said plurality of iron cores and being connected in series with said free-wheel drode and a plurality of secondary windings each passing through respective iron cores and being connected to gates and cathode terminals of respective semiconductor switching elements.
- The high voltage pulse generating circuit according to claim 4, wherein each of a semiconductor switching elements of said series circuit of a plurality of

semiconductor switching elements constituting said second switch is formed by a static induction thyristor.

- The high voltage pulse generating circuit according to claim 5, wherein said primary winding and secondary windings are wound on the iron cores by one turn.
- 7. The high voltage pulse generating circuit according to claim 5, wherein said semiconductor switch having a low withstand voltage constituting said first switch is formed by a power MOSFET.
- 8 The high voltage pulse generating circuit according to 1, wherein said second switch is turned-on again after turning-off the second switch to discharge the energy to the load.
- The high voltage pulse generating circuit according to claim 8, wherein said second switch is turned-on again for a short time period after turning-off the second switch to discharge the energy to the load.
- The high voltage pulse generating circuit according to claim 1, wherein said first and second switches are turned-off substantially simultaneously.
- The high voltage pulse generating circuit according to claim 1, wherein said second switch is turned-off immediately after said first switch is turned-off.
- 12. The high voltage pulse generating circuit according to claim 1, wherein said parallel circuit of a capacitor and a resistor is connected in series with said freewheel diode.
- The high voltage pulse generating circuit according to claim 1, wherein a resistor is connected in parallel with said free-wheel diode.
- 14. The high voltage pulse generating circuit according to claim 1, wherein said load is a discharge gap provided in a plasma generating reactor.